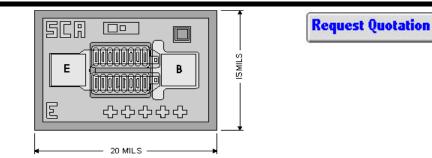


Data Sheet No. 2C3866A

Generic Packaged Parts:

2N3866, 2N3866A



Chip type **2C3866A** by Semicoa Semiconductors provides performance similar to these devices.

Part Numbers:

2N3866A, 2N3866, 2N3866AUB, SD3866A, SD3866AF, SQ3866AF, SQ3866AF

Product Summary:

APPLICATIONS: Designed for amplifier, frequency multiplier and oscillator applications. Suitable for output, driver and predriver stages in VHF and UHF equipment.

Features: Special Characteristics:

ft = 950 MHz (type) at 50 mA/15V

Mechanical Specifications					
Metallization	Тор	AI - 15 kÅ min.			
	Backside	Au - 6.5 kÅ nom.			
Bonding Pad Size	Emitter	3.4 mils x 3.0 mils			
	Base	3.4 mils x 3.0 mils			
Die Thickness	8 mils nominal				
Chip Area	15 mils x 20 mils				
Top Surface	Silox Passivated				

Electrical Characteristics $T_A = 25^{\circ}C$						
Parameter	Test conditions	Min	Max	Unit		
BV _{CEO}	I _C = 5.0 mA	30		V dc		
BV _{CBO}	I _C = 100 μA	55		V dc		
BV _{CER}	I _C = 5.0 mA, R _{BE} = 10 Ohms	55		V dc		
BV _{EBO}	I _E = 100 μA	3.5		V dc		
I _{CEO}	$V_{CE} = 28 \text{ V}, \text{ V}_{EB} = 2.0 \text{ V}$		20	μA		
h _{FE1}	$I_{\rm C}$ = 360 mA dc, $V_{\rm CE}$ = 5.0 V	5.0				
h _{FE2}	$I_{\rm C} = 50 \text{ mA dc}, V_{\rm CE} = 5.0 \text{ V}$	10	200			

Due to limitations of probe testing, only dc parameters are tested. This must be done with pulse width less than 300 μ s, duty cycle less than 2%.

